Cypress Semiconductor Corp - MB9BF568NPMC-G-JNE2 Datasheet

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What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Obsolete
Core Processor	ARM® Cortex®-M4F
Core Size	32-Bit Single-Core
Speed	160MHz
Connectivity	CANbus, CSIO, EBI/EMI, I²C, LINbus, SD, UART/USART, USB
Peripherals	DMA, LVD, POR, PWM, WDT
Number of I/O	80
Program Memory Size	1.03125MB (1.03125M x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	128K x 8
Voltage - Supply (Vcc/Vdd)	2.7V ~ 5.5V
Data Converters	A/D 24x12b; D/A 2x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 125°C (TA)
Mounting Type	Surface Mount
Package / Case	100-LQFP
Supplier Device Package	100-LQFP (14x14)
Purchase URL	https://www.e-xfl.com/product-detail/rochester-electronics/mb9bf568npmc-g-jne2

CRC (Cyclic Redundancy Check) Accelerator
The CRC accelerator helps a verify data transmission or storage integrity.

CCITT CRC16 and IEEE-802.3 CRC32 are supported.

- CCITT CRC16 Generator Polynomial: 0x1021
- IEEE-802.3 CRC32 Generator Polynomial: 0x04C11DB7

SD Card Interface
It is possible to use the SD card that conforms to the following standards.

- Part 1 Physical Layer Specification version 3.01
- Part E1 SDIO Specification version 3.00
- Part A2 SD Host Controller Standard Specification version 3.00
- 1-bit or 4-bit data bus

Clock and Reset

- Clocks

Five clock sources (2 external oscillators, 2 internal CR oscillator, and Main PLL) that are dynamically selectable.

  - Main clock: 4 MHz to 48 MHz
  - Sub Clock: 32.768 kHz
  - High-speed internal CR Clock: 4 MHz
  - Low-speed internal CR Clock: 100 kHz
  - Main PLL Clock

- Resets
  - Reset requests from INITX pin
  - Power on reset
  - Software reset
  - Watchdog timers reset
  - Low voltage detector reset
  - Clock supervisor reset

Clock Super Visor (CSV)
Clocks generated by internal CR oscillators are used to supervise abnormality of the external clocks.

- External OSC clock failure (clock stop) is detected, reset is asserted.
- External OSC frequency anomaly is detected, interrupt or reset is asserted.

Low-Voltage Detector (LVD)
This Series include 2-stage monitoring of voltage on the VCC pins. When the voltage falls below the voltage has been set, Low-Voltage Detector generates an interrupt or reset.

- LVD1: error reporting via interrupt
- LVD2: auto-reset operation

Low-power Consumption Mode
Six low-power consumption modes are supported.

- SLEEP
- TIMER
- RTC
- STOP
- Deep standby RTC (selectable from with/without RAM retention)
- Deep standby stop (selectable from with/without RAM retention)

VBAT
The consumption power during the RTC operation can be reduced by supplying the power supply independent from the RTC (calendar circuit)/32 kHz oscillation circuit. The following circuits can also be used.

- RTC
- 32 kHz oscillation circuit
- Power-on circuit
- Back up register: 32 bytes
- Port circuit

Debug
- Serial Wire JTAG Debug Port (SWJ-DP)
- Embedded Trace Macrocells (ETM) provide comprehensive debug and trace facilities.

Unique ID
Unique value of the device (41-bit) is set.

Power Supply
Three Power Supplies

- Wide range voltage:
  VCC = 2.7 V to 5.5 V
- Power supply for USB I/O:
  USBVCC = 3.0 V to 3.6 V (when USB is used)
  = 2.7 V to 5.5 V (when GPIO is used)
- Power supply for VBAT:
  VBAT = 2.7 V to 5.5 V

Pin No						Pin Name	I/O Circuit Type	Pin State Type
LQFP120	LQFP100	LQFP80	QFP100	BGA112	BGA144			
87	72	58	50	D12	D12	P22 CROUT_0 AN16 TIOB7_1 SOT0_0 (SDA0_0)	F	L
		-				ZIN1_1		
88	73	59	51	C13	D11	P21 AN17 SIN0_0 BIN1_1 INT06_1 MAD23_0	F	M
		-						
		59						
		-						
89	74	-	52	C12	C12	P20 AN18 AIN1_1 INT05_0 MAD24_0	F	M
90	75	60	53	A13	A13	VSS	-	-
91	76	61	54	B13	A12	VCC	-	-
92	77	62	55	A12	B13	P0E TIOB5_2 SCS6_1 IC13_0 S_CLK_0 MDQM1_0	L	I
93	78	63	56	B11	C10	P0D TIOA5_2 SCK6_1 (SCL6_1) IC12_0 S_CMD_0 MDQM0_0	L	I
94	79	64	57	B10	A11	P0C TIOA6_1 SOT6_1 (SDA6_1) IC11_0 S_DATA1_0 MALE_0	L	I
95	80	65	58	A10	B10	P0B TIOB6_1 SIN6_1 IC10_0 INT00_1 S_DATA0_0 MCSX0_0	L	K

Pin No						Pin Name	I/O Circuit Type	Pin State Type
LQFP120	LQFP100	LQFP80	QFP100	BGA112	BGA144			
104	89	70	67	C6	C7	P02 TDI MCSX6_0	E	H
105	90	71	68	A6	B7	P01 TCK SWCLK	E	G
106	91	72	69	B6	D6	P00 TRSTX MCSX7_0	E	H
107	92	-	70	A5	A7	VSS	-	-
108	-	-	-	-	C6	P68 TIOB7_2 SCK3_0 (SCL3_0) INT00_2	E	K
109	-	-	-	-	B6	P67 TIOA7_2 SOT3_0 (SDA3_0)	E	I
110	-	-	-	-	A6	P66 ADTG_8 SIN3_0 INT11_2	E	K
111	-	-	-	-	D5	P65 TIOB7_0 SCK5_1 (SCL5_1)	E	I
112	-	-	-	-	C5	P64 TIOA7_0 SOT5_1 (SDA5_1) INT10_2	E	K
113	93	73	71	C5	B5	P63 CROUT_1 RX0_2	E	K
	-	-	-	-		SIN5_1		
	93	73	71	C5		INT03_0 S_CD_0 MWEX_0		
114	94	74	72	B5	C4	P62 ADTG_3 TX0_2 SIN5_0 INT04_1 S_WP_0 MOEX_0	I	K

Pin Function	Pin Name	Function Description	Pin No					
			LQFP 120	LQFP 100	LQFP 80	QFP 100	BGA 112	BGA 144
Debugger	SWCLK	Serial wire debug interface clock input pin	105	90	71	68	A6	B7
	SWDIO	Serial wire debug interface data input / output pin	103	88	69	66	B7	D7
	SWO	Serial wire viewer output pin	102	87	68	65	C7	B8
	TCK	JTAG test clock input pin	105	90	71	68	A6	B7
	TDI	JTAG test data input pin	104	89	70	67	C6	C7
	TDO	JTAG debug data output pin	102	87	68	65	C7	B8
	TMS	JTAG test mode state input/output pin	103	88	69	66	B7	D7
	TRACECLK	Trace CLK output pin of ETM	101	86	-	64	C8	C8
	TRACED0	Trace data output pin of ETM	97	82	-	60	B9	C9
	TRACED1		98	83	-	61	C9	B9
	TRACED2		99	84	-	62	A8	A9
	TRACED3		100	85	-	63	B8	D8
	TRSTX	JTAG test reset input pin	106	91	72	69	B6	D6
External Bus	MAD00_0	External bus interface address bus	27	22	17	100	K2	K2
	MAD01_0		28	23	18	1	L1	K3
	MAD02_0		29	24	19	2	L2	L1
	MAD03_0		47	42	32	20	L7	L7
	MAD04_0		48	43	33	21	L8	K7
	MAD05_0		49	44	34	22	M9	M8
	MAD06_0		50	45	35	23	L9	L8
	MAD07_0		62	52	41	30	L13	L12
	MAD08_0		63	53	42	31	L12	K12
	MAD09_0		64	54	43	32	K13	K11
	MAD10_0		65	55	44	33	K12	J12
	MAD11_0		66	56	45	34	J13	J11
	MAD12_0		67	57	46	35	J12	J10
	MAD13_0		68	58	47	36	J11	H12
	MAD14_0		69	59	48	37	H12	H11
	MAD15_0		74	64	53	42	H11	H10
	MAD16_0		75	65	54	43	G12	G12
	MAD17_0		76	66	55	44	G11	G11
	MAD18_0		77	67	56	45	F12	G10
	MAD19_0		78	68	-	46	F11	F13
	MAD20_0		79	69	-	47	E12	F12
	MAD21_0		80	70	-	48	E11	F11
	MAD22_0		86	71	-	49	D13	D13
	MAD23_0		88	73	-	51	C13	D11
	MAD24_0		89	74	-	52	C12	C12

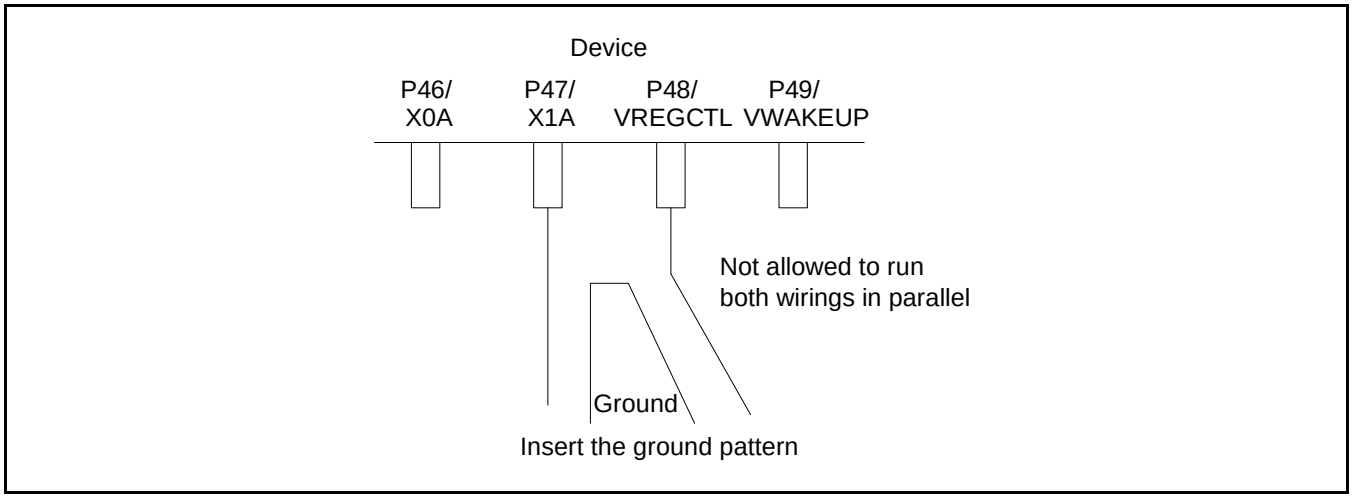
Pin Function	Pin Name	Function Description	Pin No					
			LQFP 120	LQFP 100	LQFP 80	QFP 100	BGA 112	BGA 144
Multi-function Serial 6	SIN6_0	Multi-function serial interface ch.6 input pin	7	7	7	85	E1	E1
	SIN6_1		95	80	65	58	A10	B10
	SOT6_0 (SDA6_0)	Multi-function serial interface ch.6 output pin. This pin operates as SOT6 when it is used in a UART/CSIO/LIN (operation modes 0 to 3) and as SDA6 when it is used in an I^2C (operation mode 4).	8	8	8	86	E2	E2
	SOT6_1 (SDA6_1)		94	79	64	57	B10	A11
	SCK6_0 (SCL6_0)	Multi-function serial interface ch.6 clock I/O pin. This pin operates as SCK6 when it is used in a CSIO (operation modes 2) and as SCL6 when it is used in an I^2C (operation mode 4).	9	-	-	-	-	E3
	SCK6_1 (SCL6_1)		93	78	63	56	B11	C10
	SCS6_1	Multi-function serial interface ch.6 serial chip select pin	92	77	62	55	A12	B13
Multi-function Serial 7	SIN7_0	Multi-function serial interface ch.7 input pin	101	86	-	64	C8	C8
	SIN7_1		50	45	35	23	L9	L8
	SOT7_0 (SDA7_0)	Multi-function serial interface ch.7 output pin. This pin operates as SOT7 when it is used in a UART/CSIO/LIN (operation modes 0 to 3) and as SDA7 when it is used in an I^2C (operation mode 4).	100	85	-	63	B8	D8
	SOT7_1 (SDA7_1)		49	44	34	22	M9	M8
	SCK7_0 (SCL7_0)	Multi-function serial interface ch.7 clock I/O pin. This pin operates as SCK7 when it is used in a CSIO (operation modes 2) and as SCL7 when it is used in an I^2C (operation mode 4).	99	84	-	62	A8	A9
	SCK7_1 (SCL7_1)		48	43	33	21	L8	K7
	SCS7_1	Multi-function serial interface ch.7 serial chip select pin	47	42	32	20	L7	L7

Pull-Up Function of 5 V Tolerant I/O

Please do not input the signal more than VCC voltage at the time of pull-up function use of 5V tolerant I/O.

Adjoining Wiring on Circuit Board

If wiring of the crystal oscillation circuit X1A adjoins and also runs in parallel with the wiring of P48/VREGCTL, there is a possibility that the oscillation erroneously counts because X1A has noise with the change of P48/VREGCTL. Keep as much distance as possible between both wirings and insert the ground pattern between them in order to avoid this possibility.



Handling when Using Debug Pins

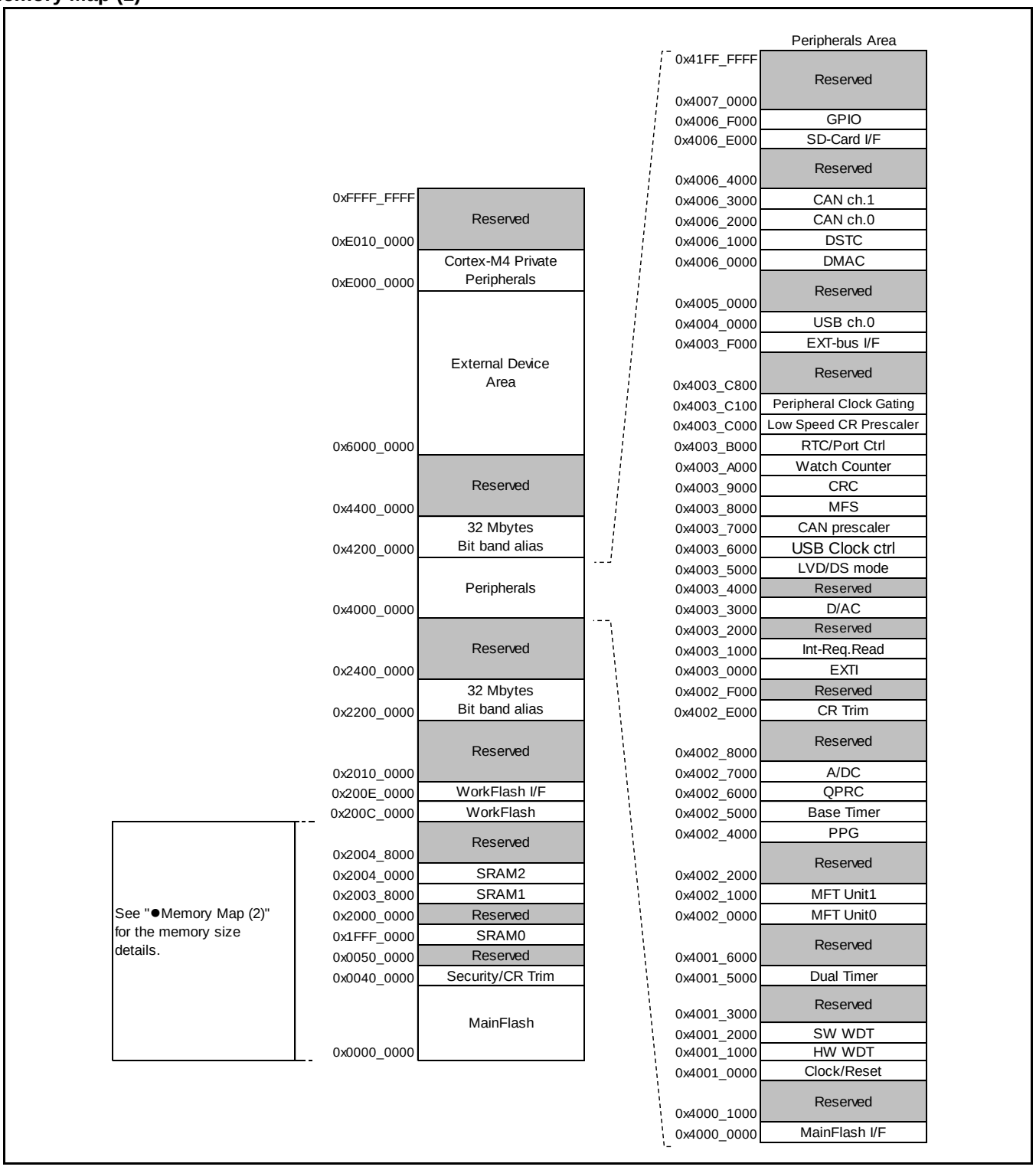
When debug pins (TDO/TMS/TDI/TCK/TRSTX or SWO/SWDIO/SWCLK) are set to GPIO or other peripheral functions, only set them as output, do not set them as input.

9. Memory Size

See Memory size in 1. Product Lineup to confirm the memory size.

10. Memory Map

Memory Map (1)



11. Pin Status in Each CPU State

The terms used for pin status have the following meanings.

■INITX=0
This is the period when the INITX pin is the L level.

■INITX=1
This is the period when the INITX pin is the H level.

■SPL=0
This is the status that the standby pin level setting bit (SPL) in the standby mode control register (STB_CTL) is set to 0.

■SPL=1
This is the status that the standby pin level setting bit (SPL) in the standby mode control register (STB_CTL) is set to 1.

■Input enabled
Indicates that the input function can be used.

■Internal input fixed at 0
This is the status that the input function cannot be used. Internal input is fixed at L.

■Hi-Z
Indicates that the pin drive transistor is disabled and the pin is put in the Hi-Z state.

■Setting disabled
Indicates that the setting is disabled.

■Maintain previous state
Maintains the state that was immediately prior to entering the current mode.
If a built-in peripheral function is operating, the output follows the peripheral function.
If the pin is being used as a port, that output is maintained.

■Analog input is enabled
Indicates that the analog input is enabled.

■Trace output
Indicates that the trace function can be used.

■GPIO selected
In Deep standby mode, pins switch to the general-purpose I/O port.

■Setting prohibition
Prohibition of a setting by specification limitation.

Pin status Type	Function Group	Power-on Reset or Low-voltage Detection State	INITX Input State	Device Internal Reset State	Run Mode or SLEEP Mode State	TIMER Mode, RTC Mode, or STOP Mode State		Deep Standby RTC Mode or Deep Standby STOP Mode State		Return from Deep Standby Mode State
		Power Supply Unstable	Power Supply Stable		Power Supply Stable	Power Supply Stable		Power Supply Stable		Power Supply Stable
		-	INITX=0	INITX=1	INITX=1	INITX=1		INITX=1		INITX=1
		-	-	-	-	SPL=0	SPL=1	SPL=0	SPL=1	-
E	Mode input pin	Input enabled	Input enabled	Input enabled	Input enabled	Input enabled	Input enabled	Input enabled	Input enabled	Input enabled
	GPIO selected	Setting disabled	Setting disabled	Setting disabled	Maintain previous state	Maintain previous state	Hi-Z / Input enabled	GPIO selected	Hi-Z / Input enabled	GPIO selected
F	NMIX selected	Setting disabled	Setting disabled	Setting disabled	Maintain previous state	Maintain previous state	Maintain previous state	WKUP input enabled	Hi-Z / WKUP input enabled	GPIO selected
	Resource other than above selected	Hi-Z	Hi-Z / Input enabled	Hi-Z / Input enabled			Hi-Z / Internal input fixed at 0			
	GPIO selected									Maintain previous state
G	JTAG selected	Hi-Z	Pull-up / Input enabled	Pull-up / Input enabled	Maintain previous state	Maintain previous state	Maintain previous state	Maintain previous state	Maintain previous state	Maintain previous state
	GPIO selected	Setting disabled	Setting disabled	Setting disabled			Hi-Z / Internal input fixed at 0	GPIO selected Internal input fixed at 0	Hi-Z / Internal input fixed at 0	GPIO selected
H	JTAG selected	Hi-Z	Pull-up / Input enabled	Pull-up / Input enabled	Maintain previous state	Maintain previous state	Maintain previous state	Maintain previous state	Maintain previous state	Maintain previous state
	Resource other than above selected	Setting disabled	Setting disabled	Setting disabled			Hi-Z / Internal input fixed at 0	GPIO selected Internal input fixed at 0	Hi-Z / Internal input fixed at 0	GPIO selected
	GPIO selected									
I	Resource selected	Hi-Z	Hi-Z / Input enabled	Hi-Z / Input enabled	Maintain previous state	Maintain previous state	Hi-Z / Internal input fixed at 0	GPIO selected Internal input fixed at 0	Hi-Z / Internal input fixed at 0	GPIO selected
	GPIO selected									

List of VBAT Domain Pin Status

VBAT Pin Status Type	Function Group	Power-on Reset*1	INITX Input State	Device Internal Reset State	Run Mode or Sleep Mode State	Timer Mode, RTC Mode, or Stop Mode State		Deep Standby RTC Mode or Deep Standby Stop Mode State		Return from Deep Standby Mode State	VBAT RTC Mode State	Return from VBAT RTC Mode State
		Power Supply Unstable	Power Supply Stable		Power Supply Stable	Power Supply Stable		Power Supply Stable		Power Supply Stable	Power Supply Stable	Power Supply Stable
		-	INITX=0	INITX=1	INITX=1	INITX=1		INITX=1		INITX=1	-	-
		-	-	-	-	SPL=0	SPL=1	SPL=0	SPL=1	-	-	-
S	GPIO selected	Setting disabled	Maintain previous state	Maintain previous state	Maintain previous state	Maintain previous state	Maintain previous state	Maintain previous state	Maintain previous state	Maintain previous state	Setting prohibition	-
S	Sub crystal oscillator input pin / External sub clock input selected	Input enabled	Input enabled	Input enabled	Input enabled	Input enabled	Input enabled	Input enabled	Input enabled	Input enabled	Maintain previous state	Maintain previous state
T	GPIO selected	Setting disabled	Maintain previous state	Maintain previous state	Maintain previous state	Maintain previous state	Maintain previous state	Maintain previous state	Maintain previous state	Maintain previous state	Setting prohibition	-
T	External sub clock input selected	Setting disabled	Maintain previous state	Maintain previous state	Maintain previous state	Maintain previous state	Maintain previous state	Maintain previous state	Maintain previous state	Maintain previous state	Maintain previous state	Maintain previous state
T	Sub crystal oscillator output pin	Hi-Z / Internal input fixed at 0/ or Input enable	Maintain previous state	Maintain previous state	Maintain previous state	Maintain previous state/ When oscillation stops, Hi-Z*2	Maintain previous state/ When oscillation stops, Hi-Z*2	Maintain previous state/ When oscillation stops, Hi-Z*2	Maintain previous state/ When oscillation stops, Hi-Z*2	Maintain previous state	Maintain previous state	Maintain previous state
U	Resource selected	Hi-Z	Maintain previous state	Maintain previous state	Maintain previous state	Maintain previous state	Maintain previous state	Maintain previous state	Maintain previous state	Maintain previous state	Maintain previous state	Maintain previous state
U	GPIO selected											

*1: When VBAT and VCC power on.

*2: When the SOSCNTL bit in the WTOSCCNT register is 0, the sub crystal oscillator output pin is maintained in the previous state. When the SOSCNTL bit in the WTOSCCNT register is 1, oscillation is stopped at Stop mode and Deep Standby Stop mode

Table 12-4. Typical and maximum current consumption in Normal operation(other than PLL), code with data accessing running from Flash memory (flash 0 wait-cycle mode and read access 0 wait

Parameter	Symbol	Pin Name	Conditions		Frequency*4	Value		Unit	Remarks
						Typ*1	Max*2		
Power supply current	I_{CC}	VCC	Normal operation (built-in high-speed CR)	*5	4 MHz	3.3	51	mA	*3 When all peripheral clocks are ON
						2.8	51	mA	*3 When all peripheral clocks are OFF
			Normal operation (sub oscillation)	*5	32 kHz	0.64	48	mA	*3 When all peripheral clocks are ON
						0.56	48	mA	*3 When all peripheral clocks are OFF
			Normal operation (built-in low-speed CR)	*5	100 kHz	0.64	48	mA	*3 When all peripheral clocks are ON
						0.58	48	mA	*3 When all peripheral clocks are OFF

*1: Ta=+25 °C, V_{CC}=3.3 V

*2: Tj=+125 °C, V_{CC}=5.5 V

*3: When all ports are fixed.

*4: Frequency is a value of HCLK. PCLK0=PCLK1=PCLK2=HCLK/2

*5: When 0 wait-cycle mode (FRWTR.RWT = 00, FSYNDN.SD = 000)

Table 12-5. Typical and maximum current consumption in Sleep operation(PLL), when PCLK0 = PCLK1 = PCLK2 = HCLK/2

Parameter	Symbol	Pin Name	Conditions	Frequency*4	Value		Unit	Remarks
					Typ*1	Max*2		
Power supply current	I_{CCS}	VCC	SLEEP operation (PLL)	160 MHz	35	84	mA	*3 When all peripheral clocks are ON
				144 MHz	32	81		
				120 MHz	27	76		
				100 MHz	23	72		
				80 MHz	19	68		
				60 MHz	15	64		
				40 MHz	11	60		
				20 MHz	6.5	55		
				8 MHz	4.1	53		
				4 MHz	3.3	52		
				160 MHz	16	65	mA	*3 When all peripheral clocks are OFF
				144 MHz	14	63		
				120 MHz	12	61		
				100 MHz	11	60		
				80 MHz	9.0	58		
				60 MHz	7.4	56		
				40 MHz	5.6	54		
				20 MHz	3.9	53		
				8 MHz	2.9	52		
				4 MHz	2.6	51		

Parameter	Symbol	Pin Name	Condition	Value		Unit	Remarks
				Min	Max		
Reset input time	t_{INITX}	INITX	-	500	-	ns	

12.4.8 Power-on Reset Timing

(V_{SS} = 0V, T_A = - 40°C to + 85°C)

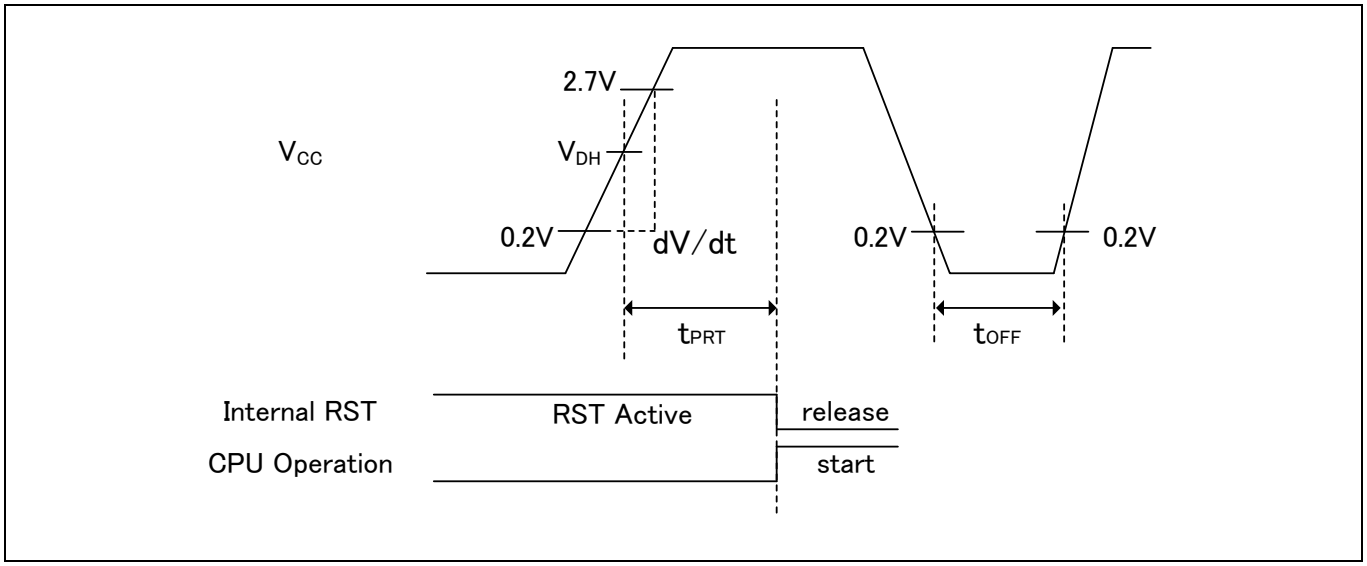
Parameter	Symbol	Pin Name	Conditions	Value			Unit	Remarks
				Min	Typ	Max		
Power supply shut down time	t_{OFF}	VCC	-	50	-	-	ms	*1
Power ramp rate	dV/dt		V_{CC}: 0.2V to 2.70V	1.3	-	1000	mV/µs	*2
Time until releasing Power-on reset	t_{PRT}		-	0.33	-	0.60	ms	

*1: V_{CC} must be held below 0.2V for a minimum period of t_{OFF}. Improper initialization may occur if this condition is not met.

*2: This dV/dt characteristic is applied at the power-on of cold start (t_{OFF}>50ms).

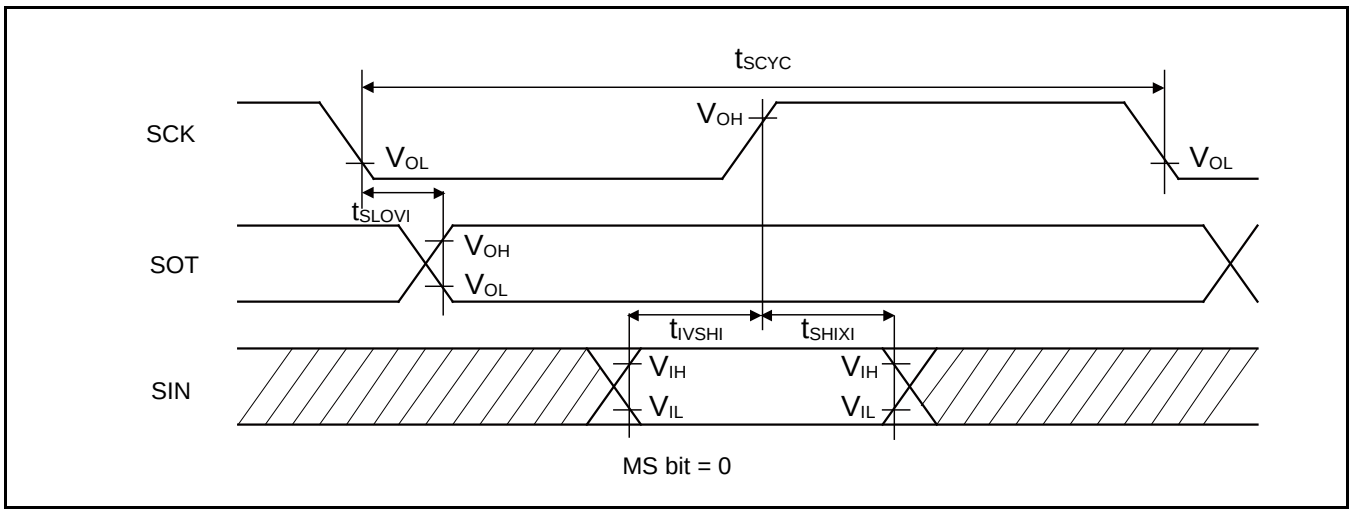
Note:

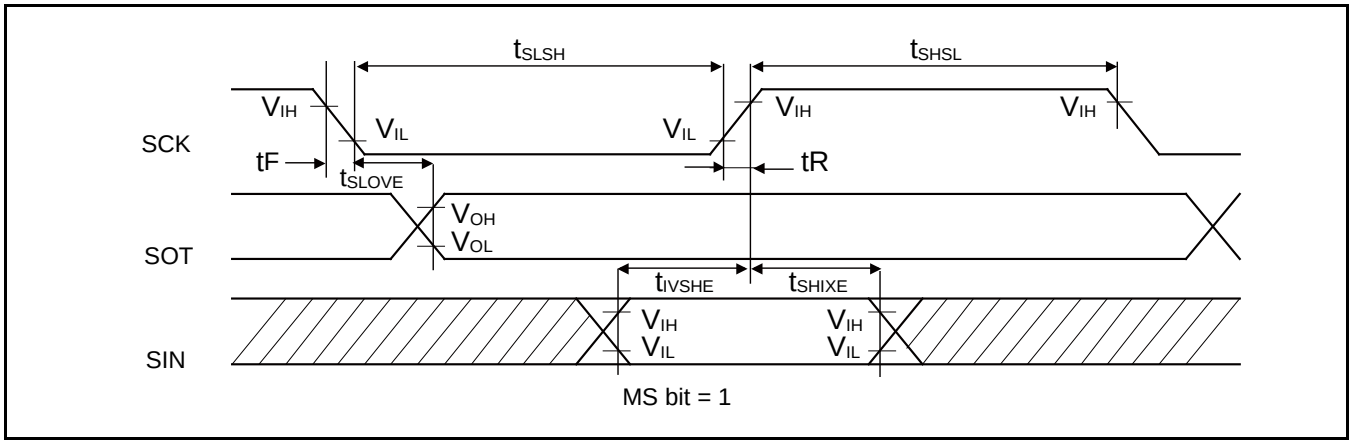
- *If t_{OFF} cannot be satisfied designs must assert external reset(INITX) at power-up and at any brownout event per 12. 4. 7.*

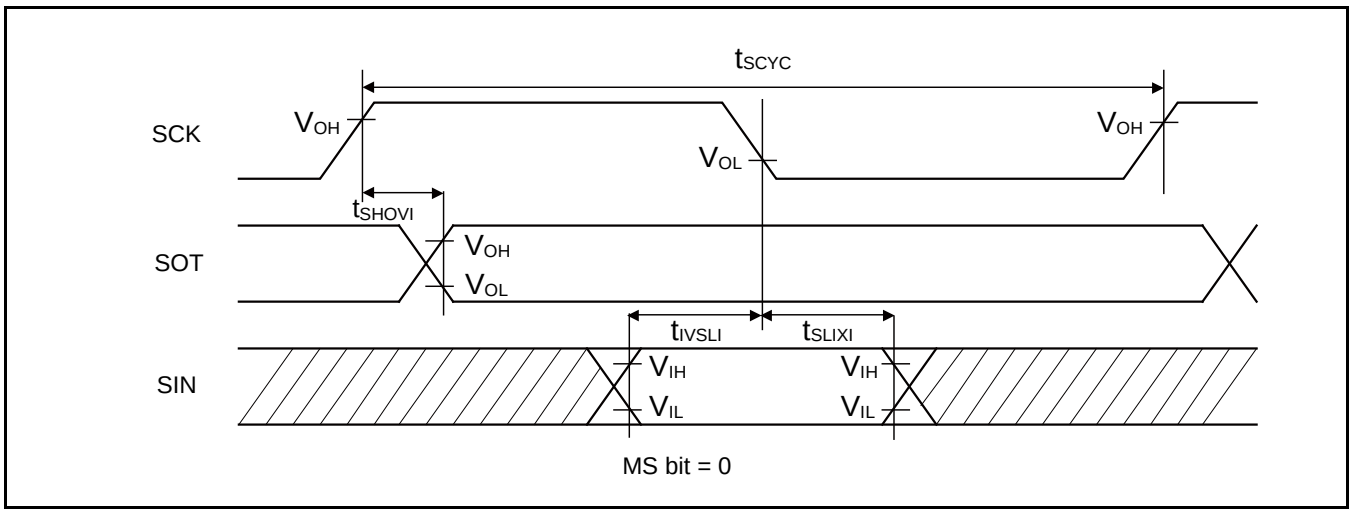


Glossary

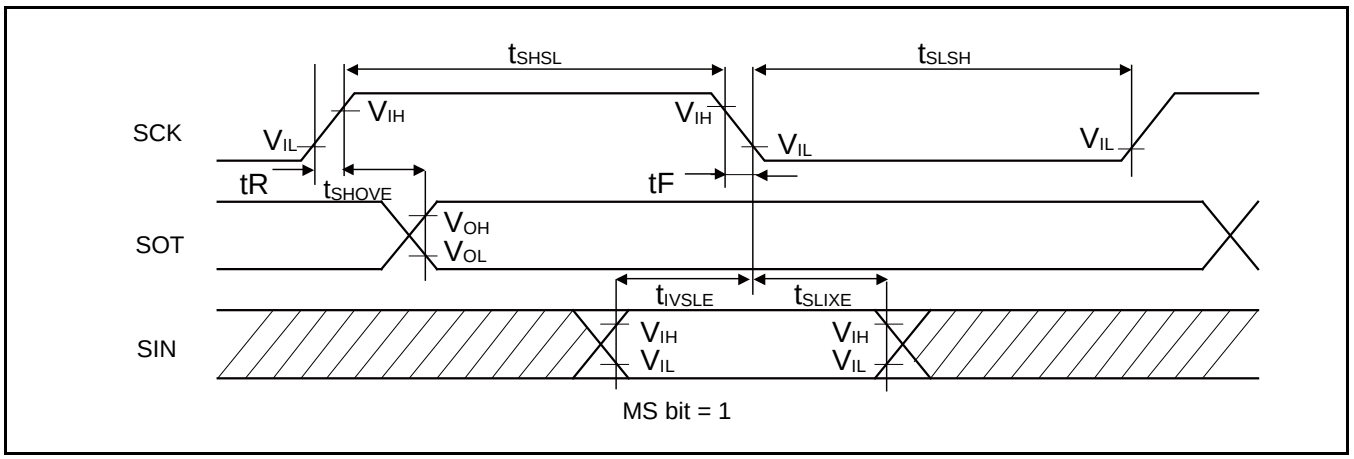
- V_{DH}: detection voltage of Low Voltage detection reset. See “12.8. Low-Voltage Detection Characteristics”.


tSCYC
SCK
VOH
VOL
VOL
tSLOVI
SOT
VOH
VOL
tIVSHI
tSHIXI
SIN
VIH
VIL
VIH
VIL
MS bit = 0


tSLSH
tSHSL
SCK
VIH
VIL
VIL
VIH
VIH
tF
tSLOVE
tR
SOT
VOH
VOL
tIVSHE
tSHIXE
SIN
VIH
VIL
VIH
VIL
MS bit = 1



MS bit = 0



MS bit = 1

When Using High-speed Synchronous Serial Chip Select (SCINV = 1, CSLVL=0)

(V_{CC} = 2.7V to 5.5V, V_{SS} = 0V)

Parameter	Symbol	Conditions	V_{CC} < 4.5 V		V_{CC} ≥ 4.5 V		Unit
			Min	Max	Min	Max	
SCS↑→SCK↑setup time	t_{CSSI}	Internal shift clock operation	(*1)-20	(*1)+0	(*1)-20	(*1)+0	ns
SCK↓→SCS↓ hold time	t_{CSHI}		(*2)+0	(*2)+20	(*2)+0	(*2)+20	ns
SCS deselect time	t_{CSDI}		(*3)-20 +5t_{CYCP}	(*3)+20 +5t_{CYCP}	(*3)-20 +5t_{CYCP}	(*3)+20 +5t_{CYCP}	ns
SCS↑→SCK↑setup time	t_{CSSE}	External shift clock operation	3t_{CYCP}+15	-	3t_{CYCP}+15	-	ns
SCK↓→SCS↓ hold time	t_{CSHE}		0	-	0	-	ns
SCS deselect time	t_{CSDE}		3t_{CYCP}+15	-	3t_{CYCP}+15	-	ns
SCS↑→SOT delay time	t_{DSE}		-	25	-	25	ns
SCS↓→SOT delay time	t_{DEE}		0	-	0	-	ns

(*1): CSSU bit value×serial chip select timing operating clock cycle [ns]

(*2): CSHD bit value×serial chip select timing operating clock cycle [ns]

(*3): CSDS bit value×serial chip select timing operating clock cycle [ns]

Notes:

- *t_{CYCP} indicates the APB bus clock cycle time.*
  About the APB bus number which UART is connected to, see 8. Block Diagram in this data sheet.
- *About CSSU, CSHD, CSDS, serial chip select timing operating clock, see FM4 Family Peripheral Manual Main part (002-04856).*
- *When the external load capacitance C_L = 30 pF.*

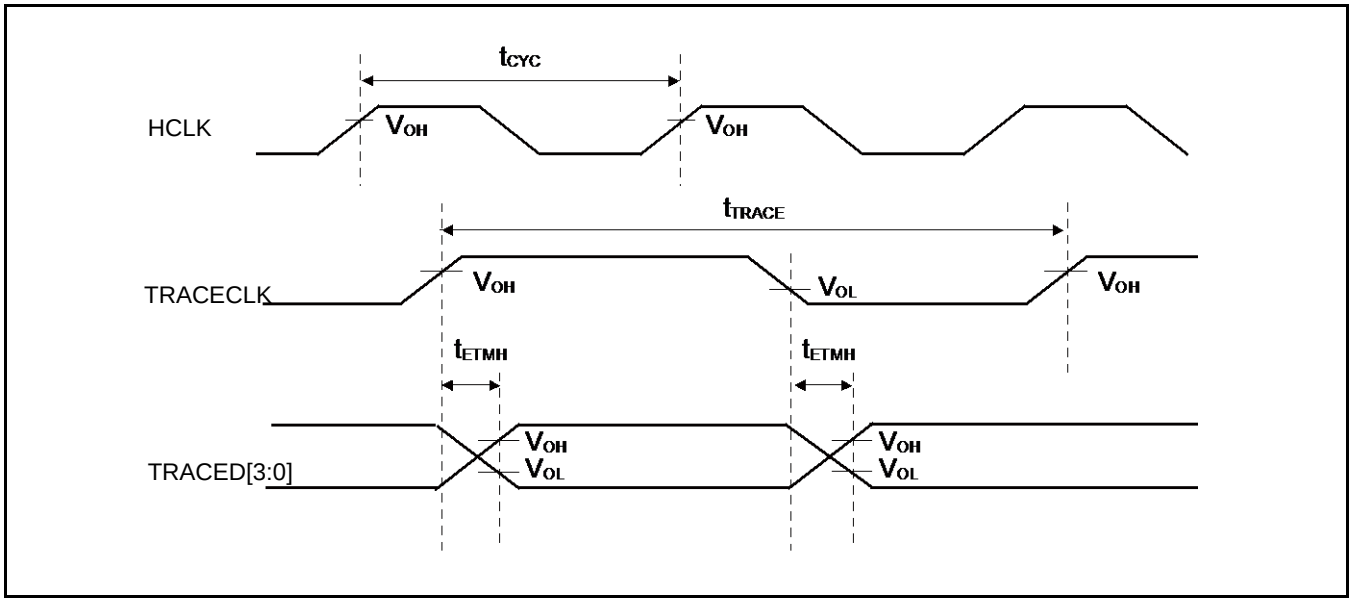
12.4.17 ETM Timing

(V_{CC} = 2.7V to 5.5V, V_{SS} = 0V)

Parameter	Symbol	Pin Name	Conditions	Value		Unit	Remarks
				Min	Max		
Data hold	t_{ETMH}	TRACECLK, TRACED[3:0]	$V_{CC} \geq 4.5$ V	2	9	ns	
			$V_{CC} < 4.5$ V	2	15		
TRACECLK frequency	1/ t_{TRACE}	TRACECLK	$V_{CC} \geq 4.5$ V	-	50	MHz	
			$V_{CC} < 4.5$ V	-	32	MHz	
TRACECLK clock cycle	t_{TRACE}		$V_{CC} \geq 4.5$ V	20	-	ns	
			$V_{CC} < 4.5$ V	31.25	-	ns	

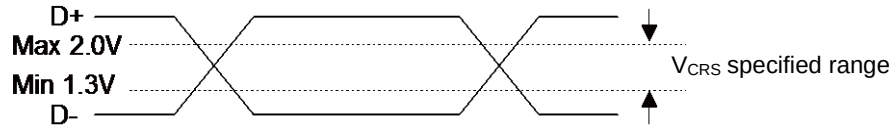
Note:

- *When the external load capacitance C_L= 30 pF.*

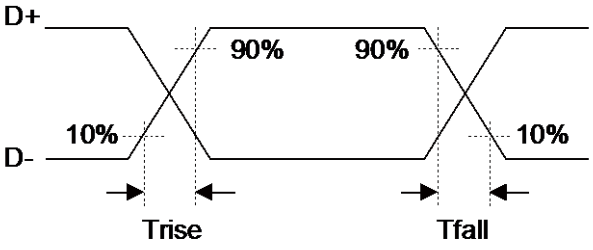


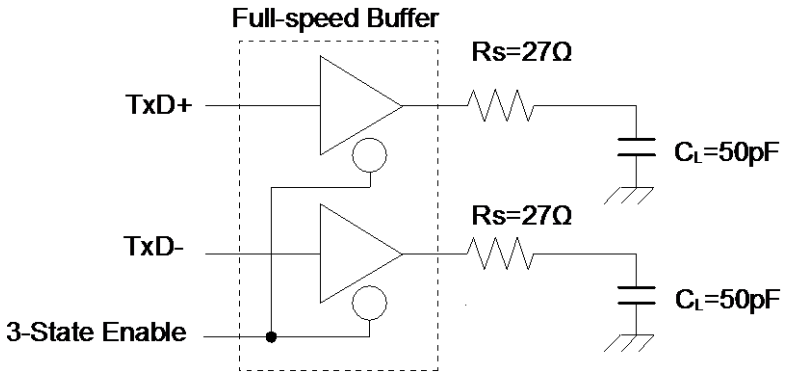
*3: The output drive capability of the driver is below 0.3 V at Low-State (V_{OL}) (to 3.6 V and 1.5 kΩ load), and 2.8 V or above (to the V_{SS} and 1.5 kΩ load) at High-State (V_{OH}).

*4: The cross voltage of the external differential output signal (D + /D −) of USB I/O buffer is within 1.3 V to 2.0 V.

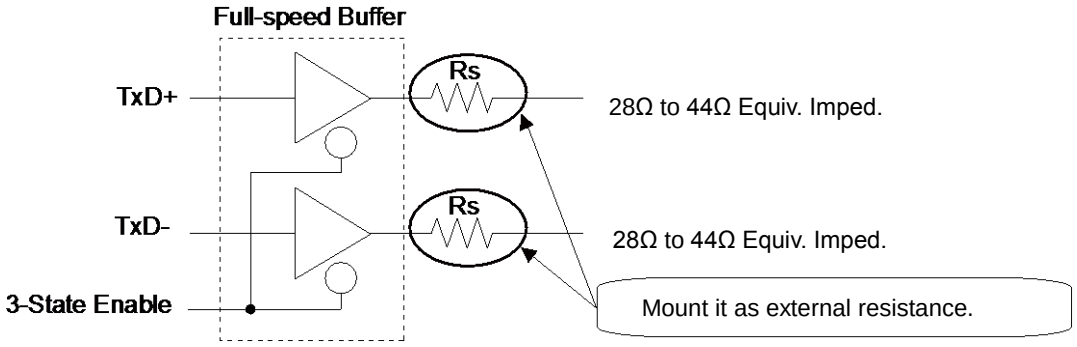


*5: They indicate rising time (Trise) and falling time (Tfall) of the full-speed differential data signal.
They are defined by the time between 10% and 90% of the output signal voltage.
For full-speed buffer, Tr/Tf ratio is regulated as within ± 10% to minimize RFI emission.





*6: USB Full-speed connection is performed via twist pair cable shield with 90 Ω ± 15% characteristic impedance (Differential Mode).
USB standard defines that output impedance of USB driver must be in range from 28 Ω to 44 Ω. So, discrete series resistor (Rs) addition is defined in order to satisfy the above definition and keep balance.
When using this USB I/O, use it with 25 Ω to 30 Ω (recommendation value 27 Ω) Series resistor Rs.

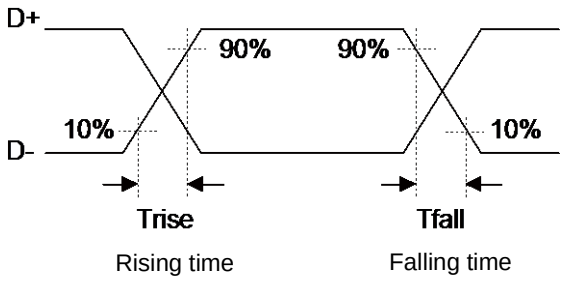


Rs series resistor 25 Ω to 30 Ω

Series resistor of 27 Ω (recommendation value) must be added.

And, use "resistance with an uncertainty of 5% by E24 sequence".

*7: They indicate rising time (Trise) and falling time (Tfall) of the low-speed differential data signal.
They are defined by the time between 10% and 90% of the output signal voltage.



See Low-Speed Load (Compliance Load) for conditions of external load.

12.9 MainFlash Memory Write/Erase Characteristics

(V_{CC} = 2.7V to 5.5V)

Parameter		Value			Unit	Remarks
		Min	Typ	Max		
Sector erase time	Large Sector	-	0.7	3.7	s	Includes write time prior to internal erase
	Small Sector		0.3	1.1		
Half word (16-bit) write time	Write cycles < 100 times	-	12	100	µs	Not including system-level overhead time
	Write cycles > 100 times			200		
Chip erase time		-	13.6	68	s	Includes write time prior to internal erase

Write cycles and data hold time

Erase/Write cycles (cycle)	Data hold time (year)
1,000	20 *
10,000	10 *
100,000	5 *

*: This value comes from the technology qualification (using Arrhenius equation to translate high temperature acceleration test result into average temperature value at +85°C) .

12.10 WorkFlash Memory Write/Erase Characteristics

(V_{CC} = 2.7V to 5.5V)

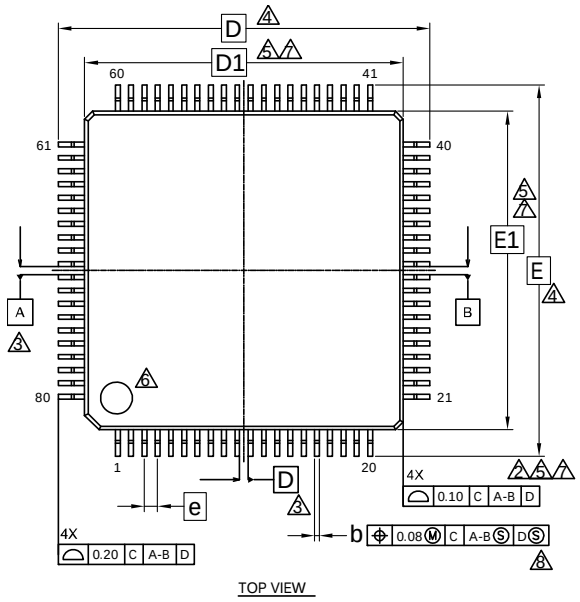
Parameter	Value			Unit	Remarks
	Min	Typ	Max		
Sector erase time	-	0.3	1.5	s	Includes write time prior to internal erase
Half word (16-bit) write time	-	20	200	µs	Not including system-level overhead time
Chip erase time	-	1.2	6	s	Includes write time prior to internal erase

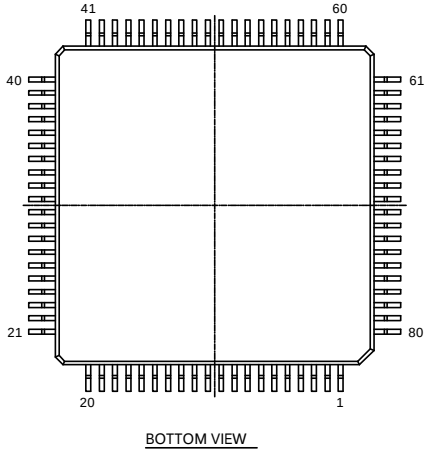
Write cycles and data hold time

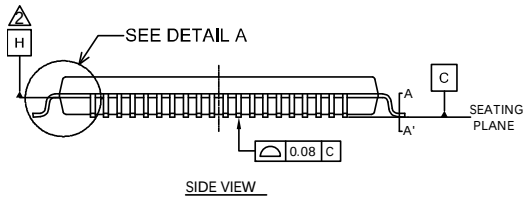
Erase/Write cycles (cycle)	Data hold time (year)
1,000	20 *
10,000	10 *
100,000	5 *

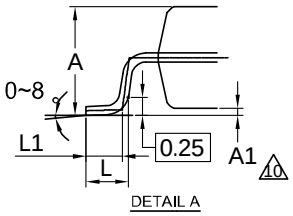
*: This value comes from the technology qualification (using Arrhenius equation to translate high temperature acceleration test result into average temperature value at +85°C) .

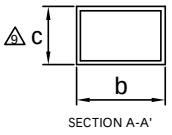
Package Type	Package Code
LQFP-80	LQH080











SYMBOL	DIMENSIONS		
	MIN.	NOM.	MAX.
A	—	—	1.70
A1	0.05	—	0.15
b	0.15	—	0.27
c	0.09	—	0.20
D	14.00 BSC.		
D1	12.00 BSC.		
e	0.50 BSC		
E	14.00 BSC.		
E1	12.00 BSC.		
L	0.45	0.60	0.75
L1	0.30	0.50	0.70

NOTES

1. CONTROLLING DIMENSIONS ARE IN MILLIMETERS (mm)
2. DATUM PLANE H IS LOCATED AT THE BOTTOM OF THE MOLD PARTING LINE COINCIDENT WITH WHERE THE LEAD EXITS THE BODY.
3. DATUMS A-B AND D TO BE DETERMINED AT DATUM PLANE H.
4. TO BE DETERMINED AT SEATING PLANE C.
5. DIMENSIONS D1 AND E1 DO NOT INCLUDE MOLD PROTRUSION. ALLOWABLE PROTRUSION IS 0.25mm PRE SIDE. DIMENSIONS D1 AND E1 INCLUDE MOLD MISMATCH AND ARE DETERMINED AT DATUM PLANE H.
6. DETAILS OF PIN 1 IDENTIFIER ARE OPTIONAL BUT MUST BE LOCATED WITHIN THE ZONE INDICATED.
7. REGARDLESS OF THE RELATIVE SIZE OF THE UPPER AND LOWER BODY SECTIONS. DIMENSIONS D1 AND E1 ARE DETERMINED AT THE LARGEST FEATURE OF THE BODY EXCLUSIVE OF MOLD FLASH AND GATE BURRS. BUT INCLUDING ANY MISMATCH BETWEEN THE UPPER AND LOWER SECTIONS OF THE MOLDER BODY.
8. DIMENSION b DOES NOT INCLUDE DAMBER PROTRUSION. THE DAMBAR PROTRUSION (S) SHALL NOT CAUSE THE LEAD WIDTH TO EXCEED b MAXIMUM BY MORE THAN 0.08mm. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE LEAD FOOT.
9. THESE DIMENSIONS APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.10mm AND 0.25mm FROM THE LEAD TIP.
10. A1 IS DEFINED AS THE DISTANCE FROM THE SEATING PLANE TO THE LOWEST POINT OF THE PACKAGE BODY.

002-11501 **

PACKAGE OUTLINE, 80 LEAD LQFP
12.0X12.0X1.7 MM LQH080 Rev **